

2SK2315

Silicon N Channel MOS FET

REJ03G1006-0200

(Previous: ADE-208-1354) Rev.2.00

Sep.07,2005

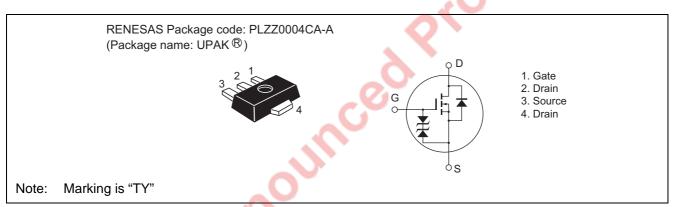
Application

High speed power switching

Features

- Low on-resistance
- High speed switching
- Low drive current
- 2.5 V gate drive device can be driven from 3 V source.
- Suitable for DC-DC converter, motor drive, power switch, solenoid drive

Outline



*UPAK is a trademark of Renesas Technology Corp.

Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit
Drain to source voltage	V_{DSS}	60	V
Gate to source voltage	V_{GSS}	±20	V
Drain current	I _D	2	А
Drain peak current	I _{D(pulse)} *1	4	А
Body to drain diode reverse drain current	I _{DR}	2	А
Channel dissipation	Pch*2	1	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1 %

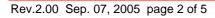
2. When using the alumina ceramic board (12.5 \times 20 \times 0.7mm)

Electrical Characteristics

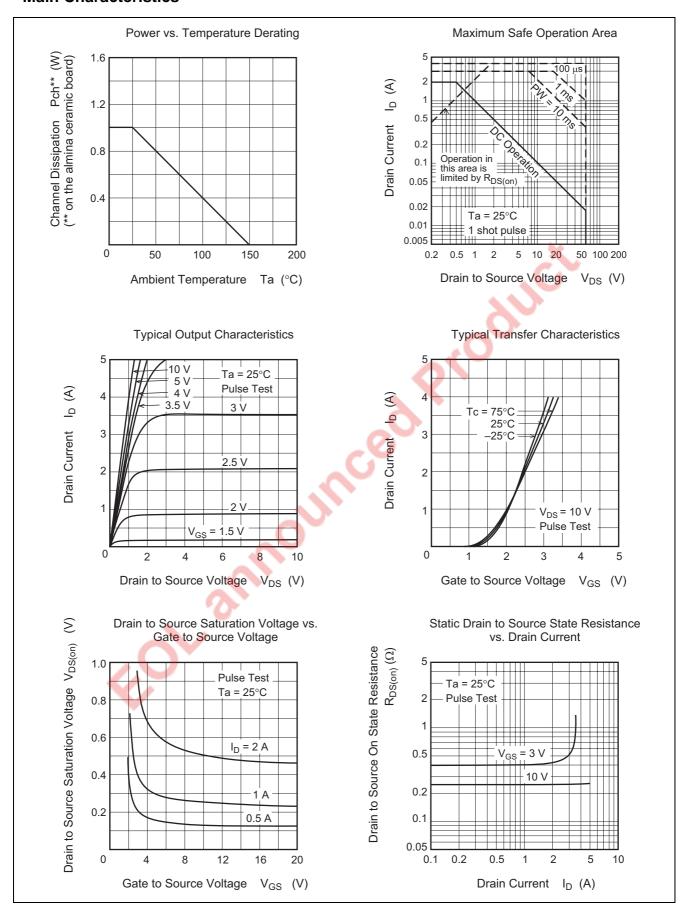
 $(Ta = 25^{\circ}C)$

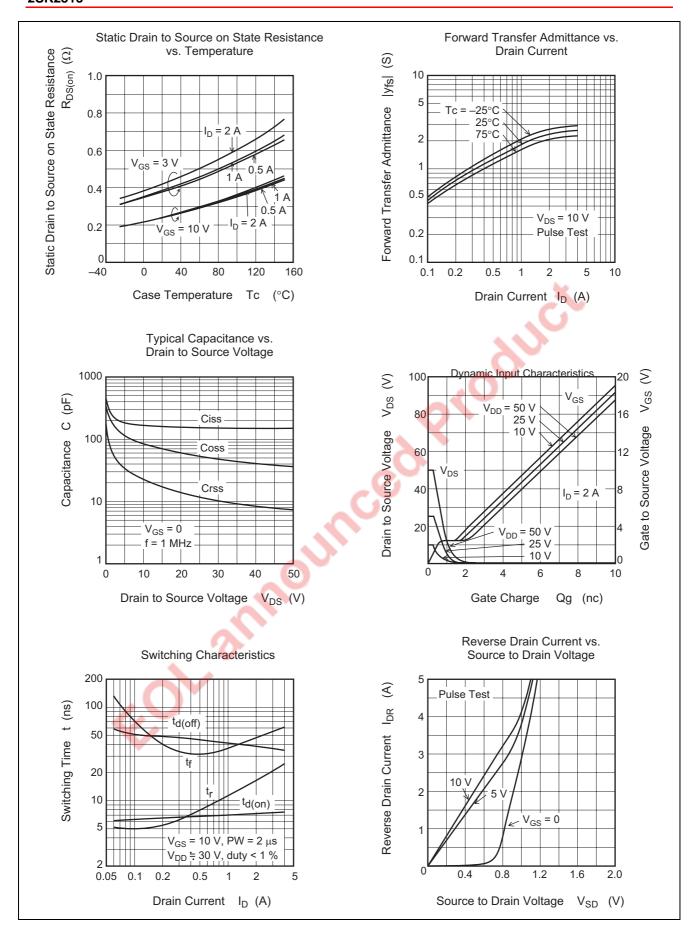
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	60	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	±20	_	_	V	$I_G = \pm 100 \mu\text{A}, V_{DS} = 0$
Gate to source leak current	I _{GSS}	_	_	±5	μΑ	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I _{DSS}	_	_	5	μΑ	$V_{DS} = 50 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	0.5	_	1.5	V	$I_D = 1 \text{ mA}, V_{DS} = 10 \text{ V}$
Static drain to source on state	R _{DS(on)}	_	0.4	0.6	Ω	$I_D = 0.3 \text{ A}, V_{GS} = 3 \text{ V}^{*3}$
resistance		_	0.35	0.45	Ω	$I_D = 1 A, V_{GS} = 4 V^{*3}$
Forward transfer admittance	y _{fs}	1.5	1.8	_	S	$I_D = 1 \text{ A}, V_{DS} = 10 \text{ V}^{*3}$
Input capacitance	Ciss	_	173	_	pF	$V_{DS} = 10 \text{ V}, V_{GS} = 0,$
Output capacitance	Coss	- 4	85	_	pF	f = 1 MHz
Reverse transfer capacitance	Crss	-	23	_	pF	
Turn-on time	t _{on}	-	21	_	ns	$I_D = 1 \text{ A}, R_L = 30 \Omega,$
Turn-off time	t _{off}	<u></u>	85	_	ns	V _{GS} = 10 V

Note: 3. Pulse Test

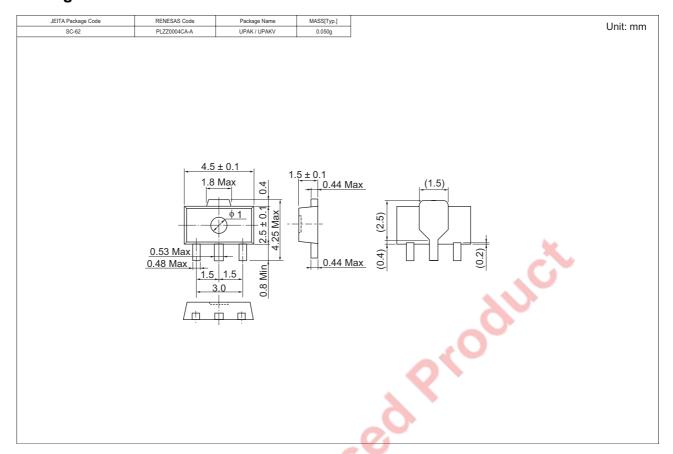


Main Characteristics





Package Dimensions



Ordering Information

Part Name	Quantity	Shipping Container
2SK2315TYTL-E	1000 pcs	Taping
2SK2315TYTR-E	1000 pcs	Taping

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.

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